

Quantum Acoustics and Acoustic Traps and Lattices for Electrons in Semiconductors

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Ikerbasque Foundation and Donostia International Physics Center



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Quantum Science and Quantum Technologies
ICTP Trieste



Collaborators on this work



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Surface Acoustic Waves for QIP

- **bosonic fields/modes play crucial role** in almost all QIP implementations (trapped ions, all photonic/quantum optical approaches, circuit-QED, ...)
- QIP in semiconductor nanostructures: still no “canonical” choice
- recent success using **surface acoustic phonons** for
 - electron transport (C Ford (Oxford), T Meunier (Grenoble): *phys stat sol (b)* **254** (2017): Ford, arXiv:1702.06628 [3] and Hermelin *et al.* [8])
 - trapping exciton-polaritons with SAWs: P Santos (PDI Berlin): de Lima & Santos, *Rep Prog Phys* **68** (2005).
 - SAW-based quantum computing: Barnes *et al.*, *PRB* **62** (2000) [1].
 - related: SAW-resonators and superconducting qubits: P Delsing (Chalmers): Gustafsson, *Science* **346** (2014) [7].
- aim of this talk: **SAWs modes as quantum bus** and **SA standing waves for acoustic lattices** for electrons

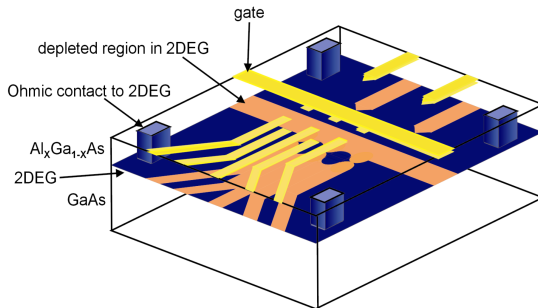
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Electrostatically defined quantum dots



- Electrically measured (contact to 2DEG)
- Electrically controlled number of electrons
- Electrically controlled tunnel barriers

Reminder: Quantum-dot Spin-qubits (cf. talk D Loss)

- proposed by Loss & DiVincenzo, PRA **57** (1998); cond-mat/9701055 [12]
- qubit: spin of electron in QD
- ✓ very compact, fast gates
($10^4 - 10^6$ operations within $T_{2,DD}$ (GaAs vs Si))
- ✓ few-qubit demonstrations
- ? long-range coupling?
- ? architecture beyond 1d arrays?
- ★ can SAWs help?

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- 1 what are surface acoustic waves...
- 2 ... and what may they be useful for?
- 3 “cavity-QED” with SAWs
- 4 acoustic lattices for electrons
- 5 summary and outlook

- phonons present in any elastic medium, **propagate within substrate**
- **surface phonons** naturally confined to within λ of surface
 - ⇒ small mode-volume
 - ⇒ trapped/guided by surface patterning
- can be augmented with **electromagnetic component** using **piezoelectric** (GaAs, ZnO) or **magnetostrictive** (terfenol-D) material

- can play the roles of optical fields and modes in the solid-state setting:
- electron transport (= optical tweezer)
- phonon-driven quantum gates (= laser-driven gates)
- acoustic lattices (= optical lattices)
- SAW resonators and waveguides as quantum bus (= cavity-QED)

Surface Acoustic Waves

- mechanical waves propagating at surface: Hooke's law and coupling to electric potential ϕ in piezoelectric materials: coupled mechanical-electrical oscillations

$$\rho \ddot{u}_i = c_{ijkl} \frac{\partial^2 u_k}{\partial x_j \partial x_l} + e_{kij} \frac{\partial^2 \phi}{\partial x_j \partial x_k}$$

$$e_{ijk} \frac{\partial^2 u_j}{\partial x_i \partial x_k} - \epsilon_{ij} \frac{\partial^2 \phi}{\partial x_i \partial x_j} = 0, \quad z > 0$$

$$\Delta \phi = 0, \quad z < 0$$

with stress-free surface boundary condition

$$c_{i\hat{z}kl} \frac{\partial u_k}{\partial x_l} = 0 + e_{ki\hat{z}} \frac{\partial \phi}{\partial x_k} \quad \text{at } z = 0$$

and continuity of $\perp$ component of electric displacement at $z = 0$

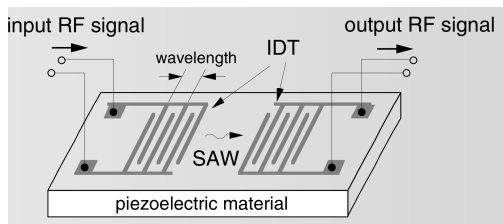
⇒ electrical excitation and detection: interdigital transducer (IDT):

- can be trapped and guided by surface-patterned structures:
- high-Q SAW resonators: $Q = 10^4 - 10^5$ [Phys. Rev. B **93** (2016);



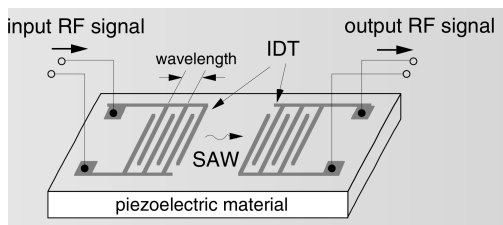
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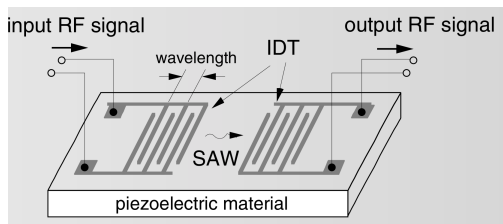
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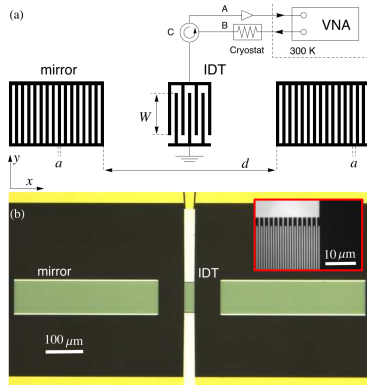
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High-Q SAW-Resonators: $Q = 10^4 - 10^5$

Surface acoustic wave resonators in the quantum regime

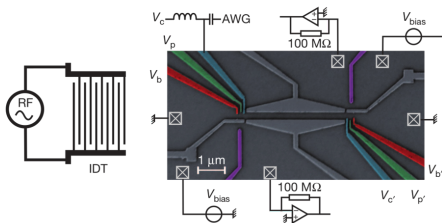
R. Manenti, M. J. Peterer, A. Nersisyan, E. B. Magnusson, A. Patterson, and P. J. Leek^{*}
Clarendon Laboratory, Department of Physics, University of Oxford, OX1 3PU, Oxford, United Kingdom
(Dated: October 19, 2015)



Classical SAWs: Moving Quantum Dots

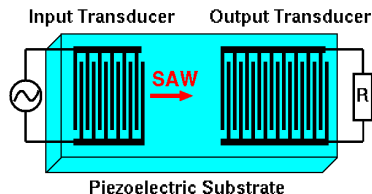
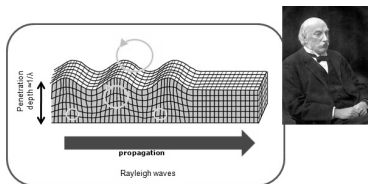
Electrons surfing on a sound wave as a platform for quantum optics with flying electrons

Sylvain Hermelin¹, Shintaro Takada², Michihisa Yamamoto^{2,3}, Seigo Tarucha^{2,4}, Andreas D. Wieck⁵, Laurent Saminadayer^{1,6}, Christopher Bäuerle¹ & Tristan Meunier¹



- proposal for quantum computing based on moving QDs [Barnes et al., 2000 [1]]

Surface Acoustic Waves: Properties



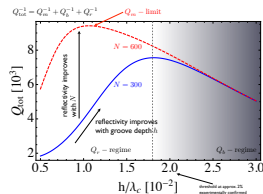
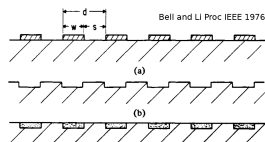
- propagate along surface, combine longitudinal and transverse motions, decay within λ away from surface
 - weak coupling to bulk waves (not phase matched)
 - frequencies: $\nu \sim 1 - 20\text{GHz}$
- ⇒ energies $\sim 10 - 100\mu\text{eV}$ ($\approx$ ground state @ 10mK (dilution fridge))
- speed $v_s \sim 3000\text{m/s}$
 - wavelength $\lambda \sim 0.5 - 10\mu\text{m}$
- ⇒ much smaller than microwave cavities at same frequency

Promising for cavity-“QAD”: SAW Resonators

- high-Q SAW resonators demonstrated (“mirrors” periodic arrays of electrodes or grooves; typically several 100)
- loss mechanisms: **diffraction losses** (finite width of reflectors), **coupling to bulk modes**, **leakage loss** through reflectors, **propagation loss**

⇒ trade-offs: small mode volume $\Rightarrow$ deep grooves $\Rightarrow$ strong bulk losses

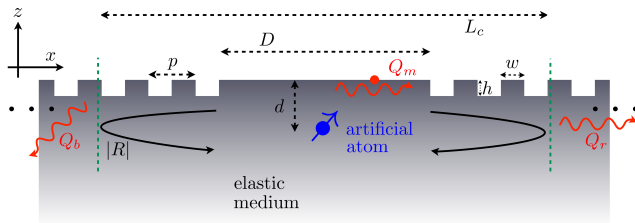
⇒ for $\lambda = 1\mu\text{m}$, quality factors $Q = 10 - 10^5$ **achievable** (for length $\sim 1 - 100\mu\text{m}$)



SAWs as a universal quantum transducer

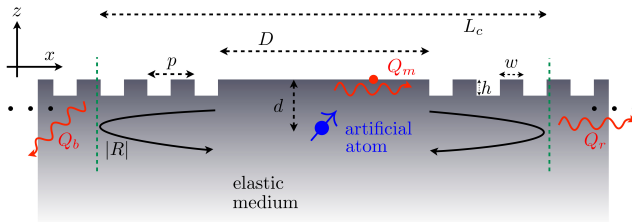
- aim: show that a variety of “standard” qubits can couple strongly to SAW cavity...
- ⇒ Jaynes-Cummings dynamics
- ⇒ on-chip long-range coupling of qubits
- ⇒ interconversion of QI between different qubits (hybrid systems)
- ⇒ prospects to have the toolbox of cavity-QED available
- ★ prototypical example: state-transfer protocol between two cavities

SAW Quantum Transducer



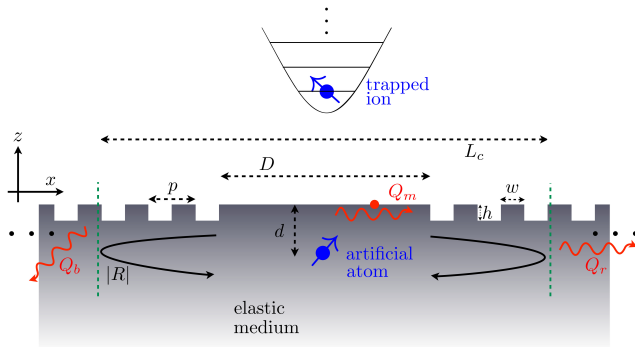
- couple resonator SAW-mode to artificial atom (QD, NV,...)

SAW Quantum Transducer



- couple resonator SAW-mode to artificial atom (QD, NV,...)
- use cavity output Q_r as quantum bus to 2nd node

SAW Quantum Transducer



- couple resonator SAW-mode to artificial atom (QD, NV,...)
- SAW field extends above surface: can also couple to qubits there

Single-phonon coupling strength and cooperativity

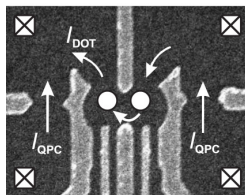
- ? which systems provide good conditions for SAW transducers?
- central quantity **cooperativity** $C = g^2 T_2 Q / [\omega_c (n_{\text{th}} + 1)]$
 $C > 1$: coherent coupling stronger than losses
can show **fidelity of state transfer** $F \approx 1 - \epsilon - \frac{1}{C}$

	charge qubit (DQD)	spin qubit (DQD)	trapped ion	NV-center
g	(200 – 450)MHz	(10 – 22.4)MHz	(1.8 – 4.0)kHz	(45 – 101)kHz
C	11 – 55	21 – 106	7 – 36	10 – 54

- ★ $C > 10$ possible in all these systems (q gates, q state transfer, ...)

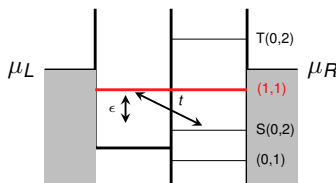
Example: Spin Qubit in Double Quantum Dot

- double QD (DQD), Coulomb blockade: (1,1) regime



[Hanson 2007]

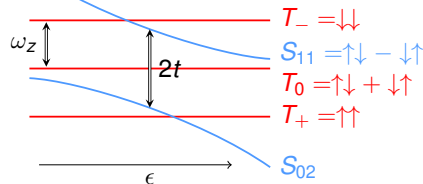
200 nm



- Hamiltonian within (1,1)-(0,2) subspace:

$$H_{el} = \omega_Z(S_L^z + S_R^z) - \epsilon|S_{02}\rangle\langle S_{02}| + t(|S_{11}\rangle\langle S_{02}| + \text{h.c.}) - \Delta(|T_0\rangle\langle S_{11}| + \text{h.c.})$$

most advanced QD qubit: two-electron
singlet-triplet qubit: $\text{span}\{|\uparrow\downarrow\rangle, |\downarrow\uparrow\rangle, |S_{02}\rangle\}$;
 all-electrical manipulation, coupling, and
 readout [Shulman et al. Science 2012 [17]]



Coupling SAWs and Quantum Dots

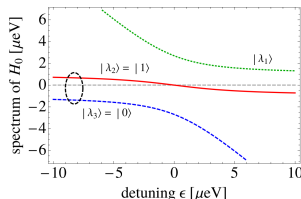
- $\lambda_{\text{SAW}} \gg$ size of DQD: add term $H_{\text{SAW}} = \sum V_{\text{SAW}}(x_i)n_i$ to H_{DQD}
- detuning of $|S_{02}\rangle$ varies periodically with V_{SAW} :

$$H = \omega_0(|T_-\rangle\langle T_-| - |T_+\rangle\langle T_+|) - \Delta B(|T_0\rangle\langle S_{11}| + \text{h.c.}) \\ + t(|S_{02}\rangle\langle S_{11}| + \text{h.c.}) - (\epsilon - \Delta V_{\text{SAW}}(t))|S_{02}\rangle\langle S_{02}|$$

three eigenstates in $S_z = 0$ subspace:

$$|\lambda_I\rangle = \alpha_I |T_0\rangle + \beta_I |S_{11}\rangle + \kappa_I |S_{02}\rangle$$

choose ω_{SAW} resonant with $|\lambda_2\rangle \leftrightarrow |\lambda_3\rangle$



$$\Rightarrow H_{\text{eff}} = \omega_{\text{eff}}(|\lambda_2\rangle\langle\lambda_2| - |\lambda_3\rangle\langle\lambda_3|) + \Omega_{\text{eff}}(a|\lambda_2\rangle\langle\lambda_3| + \text{h.c.})$$

$\Rightarrow$ single-phonon coupling strength $g_{\text{QD}} \sim 10 - 20\text{MHz}$ possible

$\Rightarrow$ single spin cooperativity $C = g_{\text{QD}}^2 T_2 / \kappa \sim 20 - 100$

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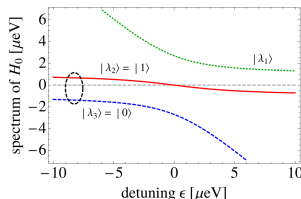
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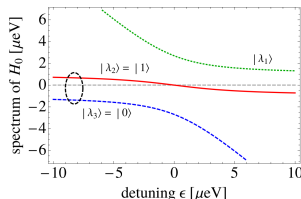
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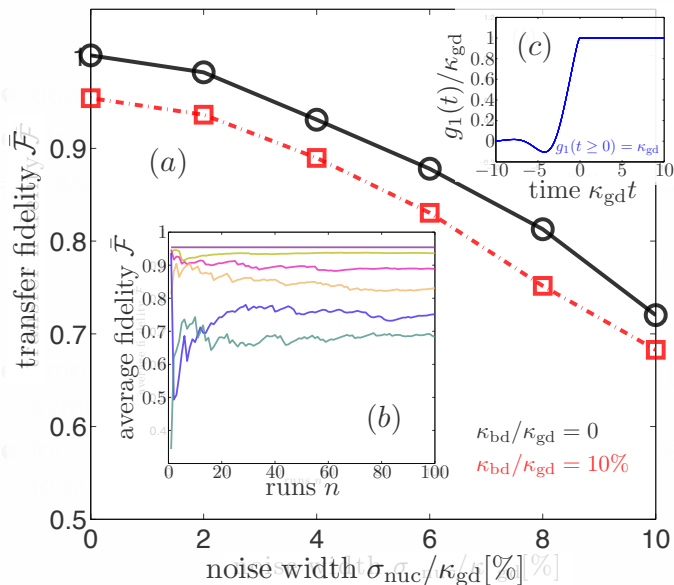
State Transfer Protocol

- goal: realize $(\alpha |0\rangle + \beta |1\rangle) \otimes |0\rangle \rightarrow |0\rangle \otimes (\alpha |0\rangle + \beta |1\rangle)$
 - place qubits in two cavities connected by wave guide
- ⇒ “cascaded quantum system”: output of first in input of 2nd cavity

$$\begin{aligned}\mathcal{L}\rho = & -i \left[H_S(t) + i\kappa_{\text{gd}} \left(a_1^\dagger a_2 - a_2^\dagger a_1 \right), \rho \right] \\ & + 2\kappa_{\text{gd}} \mathcal{D}[a_1 + a_2] \rho + \mathcal{L}_{\text{noise}} \rho\end{aligned}$$

- time dependent control pulses to optimize fidelity (time-reversal symmetric phonon wave packet)
- for small losses: **fidelity** $F = 1 - \epsilon - C^{-1}$ (C cooperativity, ϵ losses to bulk phonons)

State Transfer Protocol



$|1\rangle\rangle$

le

of 2nd cavity

$[\rho]$

time-reversal

ativity, ϵ losses

How cool do we have to be?

- for $\sim$ GHz SAWs: 10mK to reach “ground state” (dilution fridge)
- ? Experimentalist: is that really necessary??? (dilution fridge is \$\$\$)
- complications through thermal occupation: effective coupling strength unknown ($\sim g\sqrt{n_{\text{th}}}$), cavity losses enhanced ($\sim \kappa n_{\text{th}}$)
- ★ Nevertheless, Theory says: Not really! *Sørensen-Mølmer-gate* [18], *García-Ripoll-Zoller-Cirac-gate* [4] proposed for trapped ions, that work independent of motional state and make heavy use of well-tuned laser pulses
- we propose another one that does not use lasers, but relies only on integer spectrum of $a^\dagger a$

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A “hot” gate for SAW (and other) cavities

- single mode cavity, several qubits

$$H = \omega_c a^\dagger a + \frac{\omega_q}{2} S^z + gS(a + a^\dagger), S = \sum \eta_i^r \sigma_i^r$$

- for simplicity: consider limit $\omega_q \rightarrow 0$, then

$$H = \omega_c \left(a + \frac{g}{\omega_c} S \right)^\dagger \left(a + \frac{g}{\omega_c} S \right) - \frac{g^2}{\omega_c} S^2$$

★ “displaced a ” $\tilde{a} = a + \frac{g}{\omega_c} S$

⇒ H unitarily equivalent to $H_0 = \omega_c \tilde{a}^\dagger \tilde{a} - \frac{g^2}{\omega_c} S^2 = U^\dagger H U$ by polaron transformation

$$U = \exp \left[\frac{g}{\omega_c} S (a - a^\dagger) \right]$$

- since $H = UH_0U^\dagger$ we have

$$e^{itH} = Ue^{itH_0}U^\dagger = Ue^{it\omega_c a^\dagger a}e^{-it\frac{g^2}{\omega_c}S^2}U^\dagger$$

★ at $t_m = \frac{2\pi}{\omega_c}m$ the a -dependent term is $\mathbb{1}$

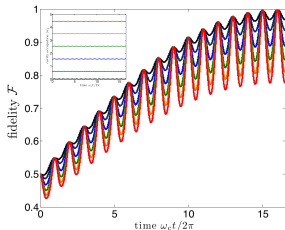
⇒ since U commutes with S we have *exactly*

$$e^{it_m H} = e^{-i2\pi m(g/\omega_c)^2 S^2}$$

independent of the motional state

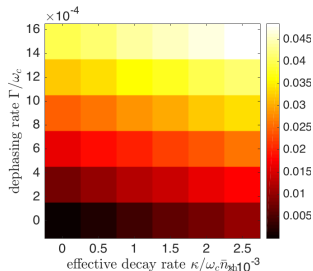
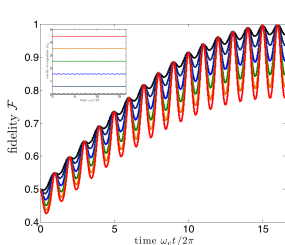
- the $e^{iT S^2}$ gate can produce Bell states, GHZ states, phase gate...
- see also Royer *et al*, Quantum **1** (2017); arXiv:1603.04424 [16].

- the scheme works



- small $\omega_q \neq 0$ can be tolerated, too...
- still T -dependent, since rate of losses $\propto \kappa n_{\text{th}}$
- good gate operation at $T = 1\text{ K}$ possible

- the scheme works even with dephasing and losses

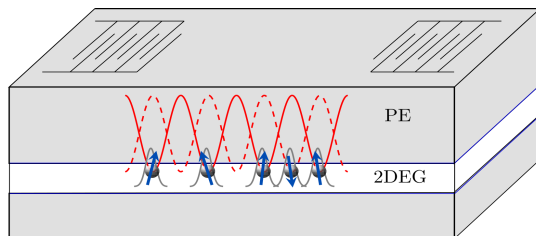


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Acoustic Lattices: Motivation

- trapping electrons in stationary 2d potential
- path to 2D architecture?
- no need for individual fabrication of quantum dots
- **quantum simulation** Hubbard model and beyond
- related work on *moving* acoustic lattices: Santos group (exp) [11]; Byrnes *et al.*, PRL 2007 [2].

General Idea



- standing SAW imposes potential landscape on electrons in 2DEG
 - rapidly oscillating force (GHz)
 - slow/inert particle sees an effective time-independent periodic potential (and can become effectively trapped at field nodes)
- ⇒ stationary, but moveable periodic potential
- ? do the numbers work out?

Acoustic Lattice I

- single electron interacting with the electric field of a single SAW
- SAW-induced potential (piezoelectric or deformation potential):

$$V(x, t) = V_{\text{SAW}} \cos(kx) \cos(\omega t)$$

⇒ classical equation of motion:

$$\frac{d^2 \tilde{x}}{d\tau^2} = 2 \frac{V_{\text{SAW}}}{m(\omega/k)^2/2} \sin(\tilde{x}) \cos(2\tau) = 0$$

- $E_s \equiv \frac{1}{2} m v_s^2 \equiv \frac{1}{2} m \frac{\omega^2}{k^2}$ and $q \equiv \frac{V_{\text{SAW}}}{E_s}$
- Lamb-Dicke regime $\tilde{x} \ll 1$: Mathieu equation

$$\frac{d^2 \tilde{x}}{d\tau^2} = 2q \cos(2\tau) \tilde{x} = 0$$

- ⇒ stability regions $0 < q < 0.92$ (cf. trapped ions!)
- ⇒ slow harmonic secular motion + fast, low-amplitude micro-motion (in stable region...)

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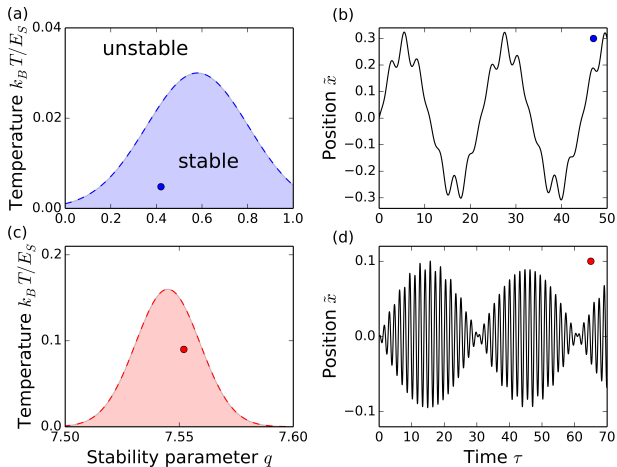
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- ⇒ **stability regions** $0 < q < 0.92$ (cf. trapped ions!)
- ⇒ slow harmonic **secular motion** + fast, low-amplitude **micro-motion** (in stable region...)

Acoustic Lattice: classical motion



Acoustic Lattice: Quantum Floquet analysis

- periodic Hamiltonian ($H_S(t + 2\pi/\omega) = H_S(t)$):

$$H_S(t) = \frac{\hat{p}^2}{2m} + V_{\text{SAW}} \cos(\omega t) \cos(k\hat{x})$$

⇒ **effective time-independent Hamiltonian** (for ω large: fast driving)

$$H_{\text{eff}} = \frac{\hat{p}^2}{2m} + V_0 \sin^2(k\hat{x})$$

$V_0 = \frac{1}{8}q^2 E_S$: **want large E_S !** (deep potential, small stab. param. q)

- (1st term of systematic expansion in ω^{-1} , cf Rahav PRA 2003)
- ★ harmonic approximation (for small kx)

$$H_{\text{eff}} \approx \frac{\hat{p}^2}{2m} + \frac{1}{2}m\omega_0^2\hat{x}^2$$

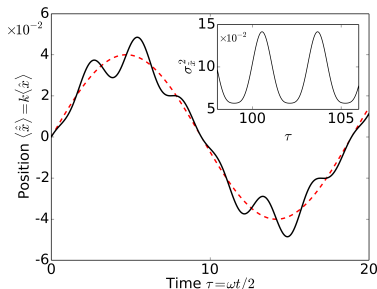
$\omega_0 = q\omega/\sqrt{8}$ secular frequency, “trap frequency”



Trajectory of trapped electron

- so far: no losses; now: **include dissipation/heating** of electron due to other phonon modes
- ⇒ **combine Floquet with Born-Markov** approx for bath [cf. Kohler *et al.*, PRE **55** (1997) [10]]
- ⇒ for $q \ll 1$, obtain time-independent Lindblad master equation for electron motion: damped harmonic oscillator

$$\dot{\rho} = -i\omega_0 [a^\dagger a, \rho] + \gamma (\bar{n}_{\text{th}}(\omega_0) + 1) \mathcal{D}[a] \rho + \gamma \bar{n}_{\text{th}}(\omega_0) \mathcal{D}[a^\dagger] \rho,$$



Working conditions

- have made a lot of approximations/assumptions
- ⇒ chain of (collectively) **sufficient conditions for good lattice:**

$$\hbar\gamma \ll k_B T \ll \hbar\omega_0 \ll \hbar\omega \ll E_S$$

- - note, in particular, that we can't just drive harder, since that moves $q = V_{\text{SAW}}/E_S$ out of stability region; nor just faster (since then we lose the bound states)
 - some typical numbers, applicable for GaAs: $\hbar\gamma \sim 0.1\mu\text{eV}$ (spont emission rate of acoustic phonons); readily compatible with $T = 10 - 100\text{mK}$ ($k_B T = 1 - 10\mu\text{eV}$); SAW frequency $\omega/2\pi = 25\text{GHz}$: $\hbar\omega = 100\mu\text{eV} \implies \hbar\omega_0 \lesssim 20\mu\text{eV}$
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- Markov approx (short correlation time $\tau_c \sim 1/k_B T$)
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- thermally stable trap, motional ground state approachable
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- separation of secular and micro-motion time scales
($q \sim \omega_0/\omega \ll 1$)
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 $\Rightarrow \ll 100\mu\text{eV}$: not promising
why? small m_e^* , small speed of sound: E_S too small
- $\Rightarrow$ increase m : holes, use other materials (larger m , larger v_s)
- $\Rightarrow$ increase v_s (higher SAW modes; diamond-boosted heterostructures [5, 6])
- $\Rightarrow$ other stability regions ($7.5 < q < 7.6$); optimized driving schemes (multi-tone)

Acoustic Lattice: Potential Setups

setup	m/m_0	$v_s[\text{km/s}]$	$E_S[\mu\text{eV}]$
electrons in GaAs*	0.067	~ 3	~ 1.7
heavy holes in GaAs**	0.45	$\sim (12 - 18)$	$\sim 184 - 415$
electrons in Si**	0.2	$\sim (12 - 18)$	$\sim 82 - 184$
holes in GaN**	1.1	$\sim (12 - 18)$	$\sim 450 - 1010$
electrons in MoS ₂ **	0.67	$\sim (12 - 18)$	$\sim 274 - 617$
trions in MoS ₂ **	1.9	$\sim (12 - 18)$	$\sim 794 - 1787$

Table: Estimates for the energy scale E_S for different physical setups. Examples marked with * refer to the lowest SAW mode in GaAs whereas those marked with ** refer to relatively fast (diamond-boosted) values of v_s in diamond-based heterostructures featuring high-frequency SAW and PSAW modes as investigated in Benetti *et al.*, APL (2005) [6], Glushkov *et al.* 2012 [5].

Applications and Issues

- ★ case study: holes in GaN quantum well on AlN/diamond; use fast SAW mode with $v_s \approx 18\text{km/s}$, $m_h = 1.1m_0$
- ⇒ RF power $P \approx 0.1\text{mW}$ (few percent of what “moving QD”-experiments use)

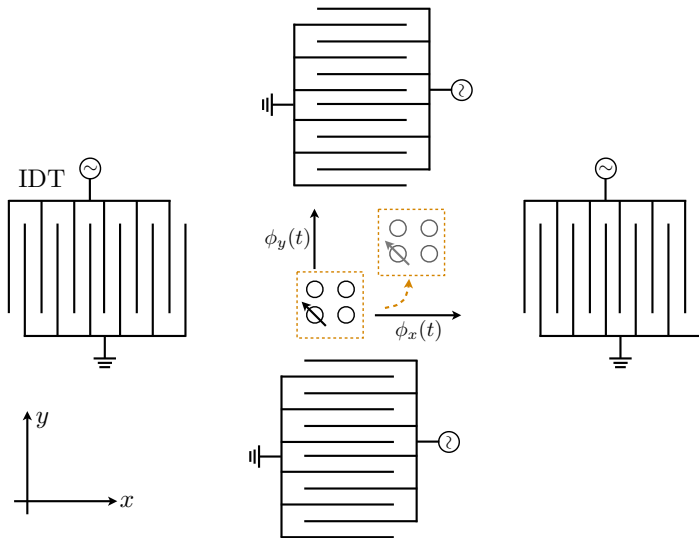
$\hbar\omega$	$q = V_{\text{SAW}}/E_S$	$\hbar\omega_0$	V_0	$n_b = V_0/\omega_0$	$\lambda/2[\text{nm}]$	$d[\text{nm}]$	t	U	$k_B T$
207	0.5 - 0.7	37-51	31-61	0.85-1.2	180	10-100	0.7-1.8	5-270	1-10

Table: Important (energy) scales (in μeV) for an exemplary setup with $E_S = 1\text{meV}$ and $f = 50\text{GHz}$. d denotes the distance between the screening layer and the 2DEG.

- movable quantum dots ($\sim 50\mu\text{eV}$ deep)
- acoustic lattices for quantum simulations: can realize Fermi Hubbard model

$$H_{\text{AFH}} = -t \sum_{\langle i,j \rangle, \sigma} \left(c_{i,\sigma}^\dagger c_{j,\sigma} + \text{h.c.} \right) + \sum_{i,\sigma} \mu_i n_i \\ + \sum_{\sigma,\sigma'} \sum_{ijkl} U_{ijkl} c_{i,\sigma'}^\dagger c_{j,\sigma}^\dagger c_{k,\sigma} c_{l,\sigma'},$$

Moving QD array



Conclusions

- SAWs provide clean and versatile on-chip method to access different established qubits (QDs, NV, trapped ions, transmons,...)
- can fill similar role as laser field/ cavity-/waveguide modes in cavity-QED and circuit-QED (“QAD”)
- SAW modes in quantum regime:
 - qubit in SAW resonator: realization of Jaynes-Cummings system
 - high cooperativities: map spin-qubits to phonons or mediate gates between different qubits
 - temperature-insensitive gates and dynamics
- classical SAW fields to trap, move, couple qubits
 - reliable electron qubit transport over sample-size distances
 - acoustic lattices for electrons or holes in quantum wells
- plenty of promise for quantum technology

Outlook: many open questions

- **quantum acoustics:**

- more flexible, scalable architectures using SAW flying qubits and SAW resonators?
- hybrid structures
- non-classical phons fields for surface physics?

- **acoustic lattices:**

- heterostructures to engineer/match SAW and quasi-particle properties
- new parameter regimes for Hubbard model / dipolar lattices?
- quantum simulation with exotic quasiparticles?

Thanks to my co-workers



J Knörzer



I Cirac



Harvard U



M Schütz



M Lukin



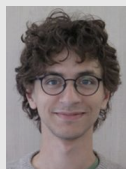
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Schuetz *et al.*, Phys. Rev. X **5** 031031 (2015); arXiv:1504.05127

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... and thank you for your attention



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Quantum Floquet Analysis

- time-periodic Hamiltonian $H(t + T) = H(t)$
- ⇒ Floquet theory (cf., e.g., Rahav et al, PRA **68**, 013820 (2003); arXiv:nlin/0301033. Bloch-Floquet theorem: eigenstates of Schrödinger equation

$$i \frac{\partial}{\partial t} |\Psi\rangle = H |\Psi\rangle ,$$

have the form

$$|\Psi_\lambda\rangle = e^{-i\lambda t} |u_\lambda(\omega t)\rangle ,$$

where u_λ periodic ($u_\lambda(x, \omega(t + T)) = u_\lambda(x, \omega t)$, with $\omega = 2\pi/T$)

- **Floquet states:** u_λ , “quasi-energy” λ
- ★ **separation of timescales:** *slow part* $e^{-i\lambda t}$ ($0 \leq \lambda < \omega$) and a *fast part* $u_\lambda(x, \omega t)$
- ⇒ find gauge transformation $|\phi\rangle = e^{iF(t)} |\Psi\rangle$ so that **effective Hamiltonian for $|\phi\rangle$ is time-independent**

$$i \frac{\partial}{\partial t} |\phi\rangle = H_{\text{eff}} |\phi\rangle ,$$

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